## NSN 5962-01-336-5579

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View Online at https://aerobasegroup.com/nsn/5962-01-336-5579 **Body Length:** 1.060 inches **Body Width:** 0.310 inches **Body Height:** 0.185 inches **Maximum Power Dissipation Rating:** 2.0 milliwatts **Operating Tempurature Range:** -55.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **Features Provided:** Monolithic and bipolar and programmed **Inclosure Material:** Ceramic **Inclosure Configuration:** Dual-in-line **Output Logic Form:** Transistor-transistor logic **Input Circuit Pattern:** 16 input **Case Outline Source And Designator:** D-8 mil-m-38510 **Terminal Surface Treatment:** Solder **Product Name:** Array, logic Voltage Rating And Type Per Characteristic: -1.5 volts power source and 12.0 volts power source **Time Rating Per Chacteristic:** 50.00 nanoseconds propagation delay time, high to low level output and 50.00 nanoseconds propagation delay time, low to high level output **Memory Device Type:** Pal **Test Data Document:** 96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.). **Terminal Type And Quantity:** 

N/a

**Unit Of Measure:** 

20 printed circuit Shelf Life:

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Demilitarization:

Yes - demil/mli

Fiig:

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